

Trans IGBT Chip N-CH 1200V 152A 830000mW

Manufacturer: <u>Littelfuse Inc</u>

Package/Case: MODULE

Product Type: Thyristors

Lifecycle: Active



Images are for reference only

Inquiry

General Description

Manufactured through the state-of-the-art GenX3TM IGBT process and an extreme-light PunchThrough (XPTTM) design platform, these devices feature high-current handling capabilities, high-speed switching abilities, low total energy losses, and low current fall times. They have a positive collector-to-emitter voltage temperature coefficient, making it possible for designers to use multiple devices in parallel to meet high current requirements. Their low gate charges also help reduce gate drive requirements and switching losses. In addition to being avalanche rated, these devices have square Reverse Bias Safe Operating Areas (RBSOA) up to the breakdown voltage– a necessary ruggedness in snubberless hard-switching applications.

Key Features	Application
Optimized for 20kHz-60kHz switching	Battery chargers
Square RBSOA	E-Bikes
Short circuit capability	Lamp ballasts
Avalanche rated	
Ultra-fast anti-parallel diodes	Power inverters
International standard packages	Power Factor Correction (PFC) circuits
Advantages:	Switched-mode power supplies
Hard-switching capability	Uninterruptible Power Supplies (UPS)
High power density	Welding machines
Low gate drive requirements	

Recommended For You

Littelfuse Inc Littelfuse Inc Littelfuse Inc

TO-247 PLUS247 TO-247

Littelfuse Inc Littelfuse Inc Littelfuse Inc

N TO-247 TO-247

Littelfuse Inc Littelfuse Inc Littelfuse Inc

TO-247 MODULE TO-247

IXGP20N120A3 IXYR50N120C3D1 IXYH50N65C3D1

Littelfuse Inc Littelfuse Inc Littelfuse Inc

TO-220 ISOPLUS247 TO-247

IXGP8N100 IXTQ460P2 IXGR48N60C3D1

Email: sales@avaq.com

Littelfuse Inc Littelfuse Inc Littelfuse Inc

TO-220 TO-3P TO-247